

Superconductor-insulator quantum critical point in $1 + \epsilon$ dimensions

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Abstract: A system of spinless fermions in $d = 1 + \epsilon$ dimensions, at zero-temperature and in random external potential is studied using the perturbative renormalization group to first order in disorder and to second order in interaction. We find a superconductor-to-Anderson insulator quantum fixed point at an infinitesimal value of disorder and calculate the correlation length and the dynamical exponents to the lowest order in ϵ and in interaction. The scaling of conductivity with temperature and the behavior of characteristic temperature scales on both sides of the transition is determined. The model may have relevance for a p-wave superconductor at low temperatures in strongly disordered media.

PACS: 74.20.Mn

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The effect of Anderson localization on superconductivity or superfluidity represents a fundamental but still incompletely understood problem in condensed matter physics. The effects of disorder may be expected to be particularly pronounced in low dimensions, $d \leq 2$, where arbitrarily weak disorder localizes all single-particle states [1] in a non-interacting system. Experiments on thin, microscopically disordered films at low temperatures, for example, have revealed a sharp separation between the insulating and superconducting regimes as some parameter controlling the amount of disorder is varied [2]. These measurements are usually interpreted as consequences of the proximity of a quantum ($T = 0$), superconductor-insulator (SI) critical point [3], [4]. Properties of such a critical point have been a subject of intense investigations in recent years [5], particularly in the context of the theory of superfluid-Bose glass transition, which assumes that the important degrees of freedom close to the transition are bosonic, preformed Cooper pairs. One of the obstacles in better quantitative understanding of the quantum SI transition lies in the fact that the assumed SI fixed point resides in the region of strong disorder, and is not easily revealed in perturbative calculations [3], [6]. A notable exemption from this rule is the SI transition in one dimension [7], [8]. At $T = 0$ and without disorder $d = 1$ is the lower critical dimension for superconductivity; only power-law superconducting correlations are possible since the true long-range superconducting order is eliminated according to Coleman-Mermin-Wagner theorem. In the language of renormalization group, this is manifested in scaling towards finite attractive fixed points [9]. When disorder is added, an immediate consequence of the special situation in $d = 1$ is that the SI fixed point is located at zero-disorder (and at finite interaction), suggesting an approach to the problem of the SI transition in higher dimensions via expansion around $d = 1$. Such an expansion would be of particular value since there may not be a finite upper critical dimension for the problem [3].

In this Letter we address some of the above issues by studying a model of interacting, disordered spinless fermions in $d = 1 + \epsilon$. The model may be appropriate for the description of the SI transition from a superconductor state with p-wave symmetry. Without disorder and for $\epsilon > 0$, the interaction coupling constant is irrelevant in infrared if positive, and runs towards $-\infty$ if negative, indicating the formation of superconducting long-range order. In the presence of disorder, we find a fixed point that controls the quantum SI transition at the value of dimensionless resistance of order ϵ , and of attractive interaction of order unity (see Figure 1). The critical exponents that characterize the fixed point are evaluated to the lowest order in ϵ and perturbatively in strength of interaction. The correlation length exponent diverges as $\epsilon \rightarrow 0$, and the dynamical exponent acquires a positive correction of order ϵ . The fact that the fixed point is infinitesimal in disorder enables one to obtain the low-temperature scaling of conductivity with temperature in simple way. Due to the pair-breaking nature of the disorder in the problem, superconducting gap vanishes at the critical point.

We consider a system of spinless fermions in d -dimensions, $1 \leq d \leq 2$, in random external potential distributed according to the probability:

$$P[V(\vec{r})] \propto \exp - \int d^d \vec{r} d^d \vec{r}' V(\vec{r}) W^{-1}(\vec{r} - \vec{r}') V(\vec{r}'). \quad (1)$$

The quantity of interest is the zero-temperature free energy $G = -\langle \ln Z \rangle$, where brackets denote averaging over disorder configurations. Utilizing the standard replica trick [10], after averaging over disorder we arrive at the zero-temperature action for fermions:

$$S = S_0 + S_{int} + S_{dis} \quad (2)$$

where,

$$S_0 = \sum_{\alpha=1}^N \int d^d \vec{K} \frac{d\omega}{2\pi} (-i\omega + e(\vec{K})) \Psi_{\alpha}^{\dagger}(\vec{K}, \omega) \Psi_{\alpha}(\vec{K}, \omega),$$

$$S_{int} = \sum_{\alpha=1}^N \int \prod_{j=1}^4 \frac{d^d \vec{K}_j d\omega_j}{(2\pi)} F(\vec{K}_1 - \vec{K}_4) \delta(\omega_1 + \omega_2 - \omega_3 - \omega_4)$$

$$\delta(\vec{K}_1 + \vec{K}_2 - \vec{K}_3 - \vec{K}_4) \Psi_{\alpha}^{\dagger}(\vec{K}_4, \omega_4) \Psi_{\alpha}^{\dagger}(\vec{K}_3, \omega_3) \Psi_{\alpha}(\vec{K}_2, \omega_2) \Psi_{\alpha}(\vec{K}_1, \omega_1),$$

and

$$S_{dis} = \sum_{\alpha, \beta=1}^N \int \left(\prod_{m=1}^4 d^d \vec{K}_m \right) \frac{d\omega_1 d\omega_2}{(2\pi)^2} W(\vec{K}_1 - \vec{K}_3) \delta(\vec{K}_1 + \vec{K}_2 - \vec{K}_3 - \vec{K}_4)$$

$$\Psi_{\alpha}^{\dagger}(\vec{K}_4, \omega_2) \Psi_{\beta}^{\dagger}(\vec{K}_3, \omega_1) \Psi_{\alpha}(\vec{K}_2, \omega_2) \Psi_{\beta}(\vec{K}_1, \omega_1).$$

Frequency integrals run over the whole real axis and the measure in $\vec{K}$ -space in d -dimensions is defined as:

$$\int d^d \vec{K} = \frac{\pi^{(d-3)/2}}{\Gamma(\frac{d-1}{2})} \int_{-\Lambda}^{\Lambda} dk \int_0^{\pi} (\sin \theta)^{d-2} d\theta, \quad (3)$$

where $e(\vec{K}) = k = |\vec{K}| - K_F$, $\Gamma(x)$ is the factorial function, and we assume a circular Fermi surface and the ultraviolet cutoff $\Lambda \ll K_F$. We set $K_F = m = \hbar = 1$. Greek indices enumerate replicas and the zero-temperature free energy is $G = \int_{\Psi} (\exp(-S) - 1)/N$, in the limit of vanishing number of replicas $N \rightarrow 0$. Note that the individual frequencies, and not only their sum, are conserved in S_{dis} , since the scattering over random impurities is elastic. This results in coupling function W having an engineering scaling like frequency (or momentum) while F is dimensionless [11], which indicates a finite scattering rate of the plane waves. We assume that the incoming (and consequently, the outgoing) momenta in both S_{dis} and S_{int} are always opposite in direction, since precisely these interactions are responsible for superconductivity [11] and weak-localization [1], [12], when present separately. Both F and W essentially depend only on angle θ between the momenta in their arguments, due to the restriction on all momenta to the vicinity of the Fermi surface, and $F(\theta) = -F(\theta + \pi)$.

When $d \rightarrow 1$, the theory becomes one-dimensional since $\int d^d \vec{K} \rightarrow \int_{-\Lambda}^{\Lambda} (dk/2\pi) \int d\theta (\delta(\theta) + \delta(\theta - \pi))$. At $d = 1$, the interaction is described by a single coupling constant $g \equiv 2(F(\theta = 0) - F(\theta = \pi))/\pi$, while disorder is determined by two coupling constants: $w_b \equiv 2W(\theta = \pi)$ for the backward, and $w_f \equiv 2W(\theta = 0)$ for the forward scattering over the random potential.

Hereafter we set $w_f = 0$, since forward scattering is unrelated to localization in $d = 1$ [13] and drop the subscript "b" in w_b . In $d = 1 + \epsilon$, $0 < \epsilon \ll 1$, for $F(\theta)$ and $W(\theta)$ smooth around $\theta = \pi$ the theory is still parametrized with only two coupling constants g and w , as defined above. To the lowest order in ϵ and disorder, β -functions then assume a general form:

$$\beta_g \equiv \frac{dg}{d\xi} = -\epsilon A(g) + \hat{w} B(g) + O(\epsilon^2, \hat{w}^2, \epsilon \hat{w}), \quad (4)$$

$$\beta_w \equiv \frac{d\hat{w}}{d\xi} = \hat{w} C(g) + O(\epsilon^2, \hat{w}^2, \epsilon \hat{w}), \quad (5)$$

where $\hat{w} = (w/k) > 0$ is the dimensionless disorder-variable, and $\xi = \ln(\Lambda/k) = \ln(\Lambda/\omega)$, where k (ω) measures the momentum (frequency) of the external legs in the renormalized disorder (interaction) vertex. We calculate the requisite functions using the standard diagrammatic perturbation theory in $d = 1$, to the second order in g :

$$A(g) = \frac{g^2 \ln 2}{2} + O(g^3), \quad (6)$$

$$B(g) = -\frac{1}{2}g + 0.10g^2 + O(g^3), \quad (7)$$

$$C(g) = 1 + g - \frac{1}{2}g^2 + O(g^3). \quad (8)$$

Function $A(g)$ is positive, so at $\hat{w} = 0$, in the infrared limit ($\xi \rightarrow \infty$) $g \rightarrow -\infty$ if initially negative, indicating the opening of a gap in spectrum and the long-range superconducting order at $T = 0$. The term proportional to ϵ in β_g comes from the increase of the phase space available for the particle-particle, relative to the particle-hole, scattering when $\epsilon > 0$, *and not*, as usually, from g acquiring a finite engineering dimension. Recall that in two and three dimensions diagrams of particle-hole type are suppressed by powers of Λ/K_F due to the restriction that all scattering processes happen in the vicinity of the Fermi surface [11]. In $d = 1$ the Fermi surface is reduced to two points, and one-loop particle-particle and particle-hole diagrams are precisely equal and opposite in sign, so they cancel out exactly. This cancelation persists to all orders in perturbation theory [14], so $\beta_g \equiv 0$ in $d = 1$ without disorder. For infinitesimal ϵ however, the homogenous system at $T = 0$ may be expected to behaves qualitatively like in higher dimensions, and our lowest-order result for $A(g)$ conforms to this expectation. The second term in β_g is positive for $g < 0$, up to two-loops for $B(g)$. This is a pair-breaking property of the disorder, which therefore always inhibits superconductivity in this model. Also, $C(g)$ becomes reduced for $g < 0$, indicating a suppression of localization by the attractive interaction in turn. The disorder-variable $\hat{w}$ scales precisely like the dimensionless resistance in $d = 1$, and the eq. 5 for $g = 0$ reduces to the statement of the Ohms law. In $d = 1 + \epsilon$ the resistance and $\hat{w}$ should be expected to be related as $R \propto \hat{w} k^\epsilon$, but this distinction between the two variables is of order of ϵ^2 in the β -functions. Staying infinitesimally close to $d = 1$ we thus may still identify $\hat{w}$ as the resistance, i. e. the right scaling variable. It is also interesting to note that the second-order

(two-loop) corrections in $B(g)$ and $C(g)$ produce only small quantitative, but no qualitative changes.

When $\epsilon = 0$ the problem has been studied before in refs. 7 and 8 within the bosonized version of the theory (2) via mapping onto the equivalent system of two-dimensional classical Coulomb plasma. Our perturbative results are in general agreement with these calculations. Some numerical differences originate in different implementation of the renormalization procedure: the coefficient of the g^2 -term in $C(g)$ is different, for example. The topology of the scaling diagram, the behavior of the conductivity at the transition and the divergence of the correlation length are the same as in our analysis at $\epsilon = 0$, these differences notwithstanding.

The main new feature brought by finite ϵ is the appearance of the finite-disorder fixed point in the physical region of the parameter space that determines the critical behavior at the quantum SI transition (Figure 1). It is located at

$$\hat{w}_c = \frac{\epsilon A(g_c)}{B(g_c)} \approx 0.42\epsilon, \quad (9)$$

$$g_c \approx 1 - \sqrt{3}, \quad (10)$$

where the numbers are obtained on the basis of the perturbative series in eqs. 6-8. Note that the fixed point is infinitesimal only in disorder and not in interaction, so our results are not exact even to the lowest order in ϵ . Interaction at the fixed-point is of order $d_\tau = 1$, the number of dimensions in directions of imaginary time. A more precise determination of the scaling equations would require a calculation and resummation of higher order terms in g . Under the assumption that there are no intermediate fixed points, scaling trajectories starting above the separatrix on Figure 1 end in the non-interacting, strongly disordered sink, which we identify with Anderson insulator. This should be contrasted with the Bose-glass phase in which tightly bound pairs of fermions would be localized. For initially positive interaction g , the scaling is always towards the insulating phase, unless $\hat{w} = 0$, when flows terminate in the trivial, unstable fixed point at the origin.

The relevant direction at the SI fixed point plays the role analogous to temperature in thermal phase transitions. The linearization of the flow in the vicinity of the fixed point yields the correlation length exponent, $L_{cor} \propto \delta^{-\nu}$:

$$\nu = \frac{1}{\sqrt{\epsilon A(g_c) C'(g_c)}} \approx \frac{1.75}{\sqrt{\epsilon}}, \quad (11)$$

where the prime denotes the derivative of the function and the parameter δ measures the distance from the transition. When $\epsilon \rightarrow 0$ the exponent ν diverges, indicating the vicinity of the lower critical dimension for the transition. The value of the exponent satisfies the Harris criterion $\nu > 2/d$ [15] for all values of ϵ . To the lowest order in disorder and interaction, the dynamical critical exponent acquires a positive correction:

$$z = 1 + \frac{\hat{w}_c}{2} + O(\hat{w}_c g_c, \hat{w}_c^2), \quad (12)$$

as a result of different treatment of frequencies and momenta by the disorder term in the action (2), which breaks the relativistic invariance of the homogeneous system.

We may define the superconducting quasi-transition temperature T_{sc} (proportional to the superconducting gap at $T = 0$), as the frequency (momentum) scale at which g diverges. When $\hat{w} = 0$, it follows from the eq. 4 that:

$$T_{0,sc} = \Lambda \exp - \frac{2}{\epsilon |g_0| \ln 2}, \quad (13)$$

where $g_0 < 0$ is the initial value of g . True superconducting temperature is of course zero for $d < 2$ due to the effect of thermal fluctuations which are not included properly in our zero-temperature theory, nevertheless, the above defined quantity sets the temperature scale at which the Cooper pairs start to form. On the superconducting side, close to the SI transition this energy scales to zero as $T_{sc} \propto \delta^{z\nu}$. The diverging size of the Cooper pairs at the transition is a consequence of the pair-breaking nature of the disorder in our model. It thus seems unlikely that the SI transition in this systems can be described by an effective bosonic theory in terms of preformed Cooper pairs.

Under the assumption that at low, but finite temperatures, scaling equations do not get substantially modified, we may infer the temperature dependence of the conductivity [8]. At the superconducting side of the transition, $\hat{w} \rightarrow 0$, and the conductivity is given by the sum of classical (Boltzmann) part and quantum (weak-localization) correction: $\sigma = \sigma_B + \sigma_Q$. According to our calculations $\hat{w}$ vanishes at some finite temperature T_{sc} , at which g diverges. At this temperature superconducting fluctuations become strong which results in dramatic reduction in resistivity. Within our approximation, σ_B actually diverges at T_{sc} , while $\sigma_Q \sim -L_T^{1-\epsilon}$, where $L_T \propto T^{-1}$ is the inelastic scattering length, remains finite. Thus $\sigma = \sigma_B$ close to T_{sc} , and in our units $\sigma_B = 1/(\hat{w}k^{1-\epsilon})$, with temperature scaling as momentum $T = k$. The behavior of $\hat{w}$ close to T_{sc} is determined by the scaling equations in the region $g \ll -1$. From the eq. (8) $C(g) \approx -g^2/2$ in this region, implying the resistivity, to the lowest order in ϵ :

$$\rho \equiv \sigma^{-1} \approx \hat{w}_0 T \exp - \frac{2T_{sc}}{\epsilon^2 (\ln 2)^2 (T - T_{sc})}. \quad (14)$$

For more general $A(g)$ and $C(g)$, we would still expect to find an activated form of the resistivity close to T_{sc} , but with the power of $(T - T_{sc})$ and the constants in the exponent modified.

On the insulating side of the transition, at low temperatures the system is in the localized phase and the transport proceeds via hopping between the localized states. The conductivity then should have an activated form, similarly (but not identically) to the resistivity in the superconducting phase close to T_{sc} :

$$\sigma \sim \exp - \left(\frac{T_{loc}}{T} \right)^\alpha, \quad (15)$$

where the power α depends on the hopping mechanism. The temperature scale $T_{loc} \sim 1/L_{loc}^z$, where L_{loc} is the localization length at the insulating side. This length may be defined as a

scale at which $\hat{w}$ becomes of order of unity upon scaling, so $L_{loc} \propto L_{cor}$ and T_{loc} also vanishes as $T_{loc} \propto \delta^{z\nu}$. In $d = 1$, $L_{loc} \propto \exp(const/\delta^{1/2})$, akin to the divergence of correlation length in the Kosterlitz-Thouless transition [8].

Right at the SI transition the resistance $\hat{w}$ has a finite value $\hat{w}_c \propto \epsilon$. The conductivity is still determined by the weak-disorder expression. Now $\sigma_B = T^{-(1-\epsilon)/z}/\hat{w}_c$ as $T \rightarrow 0$, and the quantum correction $\sigma_Q \sim T^{-(1-\epsilon)/z}$ is still negligible infinitesimally close to $d = 1$. The conductivity at the point of SI transition thus diverges as:

$$\sigma = \frac{T^{-(1-const.\epsilon)}}{\hat{w}_c}, \quad (16)$$

with $const. \approx 1.20$, to the lowest order in g . When $\epsilon = 0$, we find $\sigma = \sigma_B \propto (\ln T)^2/T$ right at the transition.

The results presented in this paper are not directly relevant for the experiments on thin films [2] due to the assumed spinless nature of fermions in our model. Disorder is not pair-breaking for the usual s-wave pairing, and the SI transition in that case should be in a different universality class, for which the theory in terms of the bosonic Cooper pairs becomes viable [5]. The transition between a p-wave superconductor and insulator, however, could be expected to be in the same universality class as the considered model. 3He in strongly disordered media [16] such as aerogels may offer an experimental realization of the quantum transition we considered.

In summary, we studied a $1 + \epsilon$ -dimensional model of interacting, disordered fermions which exhibits a direct, continuous, superconductor-Anderson insulator transition at zero temperature. The value of parameter ϵ controls the value of resistance at the quantum fixed point, and we calculated the critical exponents to the lowest order in ϵ and interaction. The behavior of conductivity at both sides of the transition is obtained, and the superconducting gap at the critical point is showed to vanish. The model may have relevance for p-wave superconductors in disordered media at low temperatures.

We acknowledge useful conversations with Professors I. Affleck, P. Stamp and Z. Tešano-vić. The author thanks NSERC of Canada and Izaak Walton Killam foundation for financial support.

Figure Captions:

Figure 1: Schematic scaling diagram in the interaction-disorder plane in $d = 1 + \epsilon$ for spinless fermions. The scaling trajectory flowing right into the fixed point separates the flows towards the superconducting ($g = -\infty, \hat{w} = 0$) phase from the flows towards the non-interacting localized insulator ($g = 0, \hat{w} = \infty$).

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